

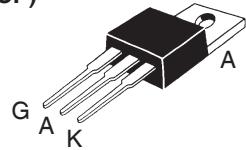
Switchable Current Regulators

IXCP 10M45S IXCY 10M45S

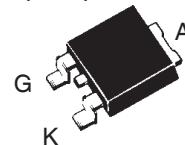
$V_{AK} = 450$ V
 $I_{A(P)} = 2 - 100$ mA
 $R_{DYN} = 9 - 900$ kΩ

Symbol	Test Condition	Maximum Ratings		
V_{AKR}	$T_J = 25^\circ\text{C}$ to 150°C	10M35S	450	V
V_{AGR}	$T_J = 25^\circ\text{C}$ to 150°C	10M35S	450	V
V_{GK}			± 20	V
I_D	$T_c = 25^\circ\text{C}$		-0.3	A
P_D	$T_c = 25^\circ\text{C}$		40	W
T_J			-55 ... +150	°C
$T_{L^{stg}}$			-55 ... +150	°C
T_L	Temperature for Soldering (max. 10 s)		260	°C
M_D	Mounting torque with screw M3 (TO-220) with screw M3.5 (TO-220)	0.45/4 0.55/5	Nm/lb.in. Nm/lb.in.	

TO-220 AB (IXCP)



TO-252 AA
(IXCY)



Pin connections

- 1 = G, Control terminal;
- 2 and 4 = A (+) Positive terminal
- 3 = K (-), Negative terminal

Features

- Minimum of 350/450 V breakdown
- Resistor programmable current source
- 40 W continuous dissipation
- International standard packages JEDEC TO-220 and TO-252
- On/Off switchable current source

Applications

- Start-up circuits for SMPS
- Highly stable voltage sources
- Surge limiters and voltage protection
- Instantaneously reacting resetable fuses
- Soft start-up circuits

Symbol	Test Condition	Characteristic Values		
		($T_J = 25^\circ\text{C}$ unless otherwise specified)	min.	typ.
V_{AKR}	$R_K = 300 \Omega$, (Fig. 4)	10M35S	450	V
$I_{A(P)}$	$V_D = 10$ V; $R_K = 300 \Omega$; (Fig. 5)		7	10
$V_{G(off)}$	$I_D = 100 \mu\text{A}$; $V_D = 400$ V Fig. 4	10M45S	-5	V
I_{AV}	$V_D = 400$ V; $V_{GK} = -10$ V Fig. 4			25 μA
$\Delta V_{AK}/\Delta I_{A(p)}$	Dynamic resistance; $V_D = 10$ V $R_K = 300 \Omega$; (Fig. 4)	160		kΩ
R_{thJC}	Thermal Resistance junction-to-case		3.1	K/W
R_{thJA}	Thermal Resistance junction-to-ambient TO-220 TO-252		80 100	K/W

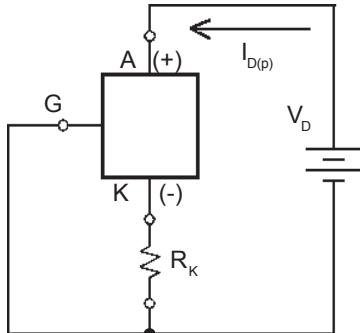


Fig. 1 Resistor R_K in series with negative pin to achieve different current levels

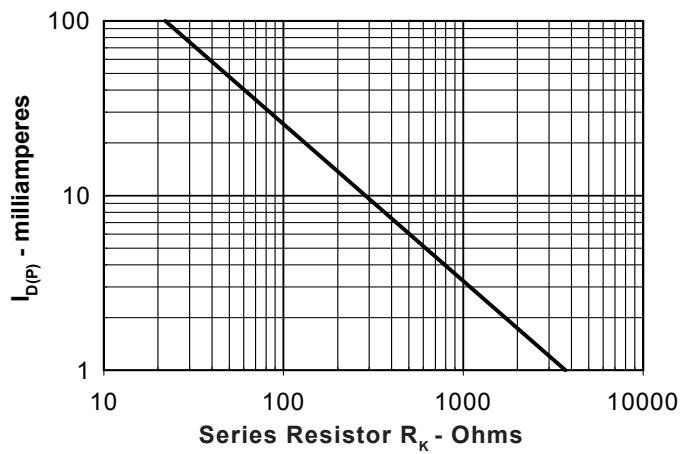


Fig. 2. Plateau current versus external resistance

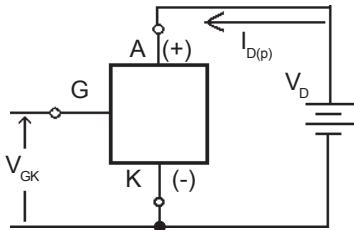


Fig. 3. Current regulator controlled by V_G

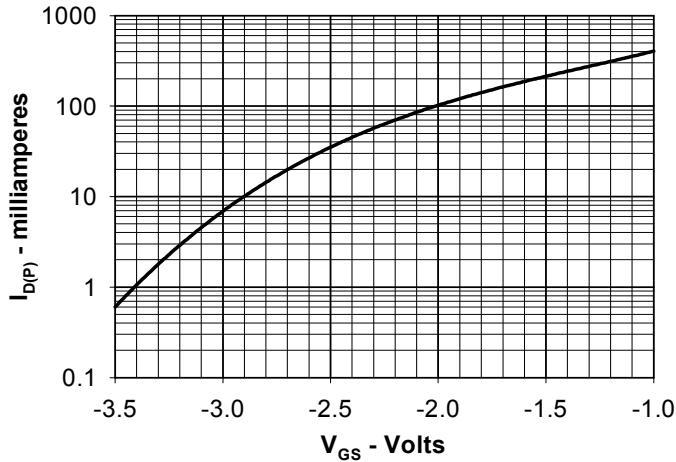
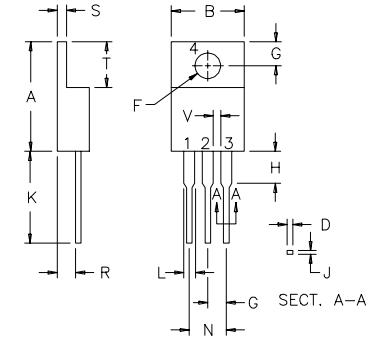


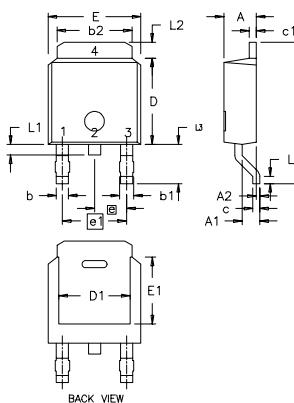
Fig. 4. Plateau current versus applied input voltage

TO-220 AB Outline



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	14.23	16.51	.560	.650
B	9.66	10.66	.380	.420
C	3.56	4.82	.140	.190
D	0.64	0.89	.025	.035
F	3.54	4.06	.139	.161
G	2.29	2.79	.090	.110
H	—	6.35	—	.250
J	0.51	0.76	.020	.030
K	12.70	14.73	.500	.580
L	1.15	1.77	.045	.070
N	4.83	5.33	.190	.210
Q	2.54	3.42	.100	.135
R	2.04	2.49	.080	.115
S	0.64	1.39	.025	.055
T	5.85	6.85	.230	.270
V	1.15	—	.045	—

TO-252 AA Outline



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	2.19	2.38	0.086	0.094
A1	0.89	1.14	0.035	0.045
A2	0	0.13	0	0.005
b	0.64	0.89	0.025	0.035
b1	0.76	1.14	0.030	0.045
b2	5.21	5.46	0.205	0.215
c	0.46	0.58	0.018	0.023
c1	0.46	0.58	0.018	0.023
D	5.97	6.22	0.235	0.245
D1	4.32	5.21	0.170	0.205
E	6.35	6.73	0.250	0.265
E1	4.32	5.21	0.170	0.205
e	2.28	BSCL	0.090	BSCL
e1	4.57	BSCL	0.180	BSCL
H	9.40	10.42	0.370	0.410
L	0.51	1.02	0.020	0.040
L1	0.64	1.02	0.025	0.040
L2	0.89	1.27	0.035	0.050
L3	2.54	2.92	0.100	0.115

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by
one or more of the following U.S. patents:
4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1
4,850,072 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343
4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505

6,683,344 6,727,585
6,710,405 B2 6,710,463